

### Description

The AU3314PE is a 3.3V bi-directional TVS diode array, utilizing leading monolithic silicon technology to provide fast response time and ultra low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The AU3314PE complies with the IEC 61000-4-2 (ESD) with  $\pm 30\text{kV}$  air and  $\pm 30\text{kV}$  contact discharge. It is assembled into DFN lead-free package. The small size and high ESD surge protection make AU3314PE an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

### Features

- Ultra low leakage: nA level
- Ultra low operating voltage: 3.3V
- Ultra low clamping voltage
- Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
    - Air discharge:  $\pm 30\text{kV}$
    - Contact discharge:  $\pm 30\text{kV}$
  - IEC61000-4-5 (Lightning) 8A (8/20 $\mu\text{s}$ )
- RoHS Compliant

### Mechanical Characteristics

- Package: DFN1510-6
- Case Material: “Green” Molding Compound.
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Below

### Applications

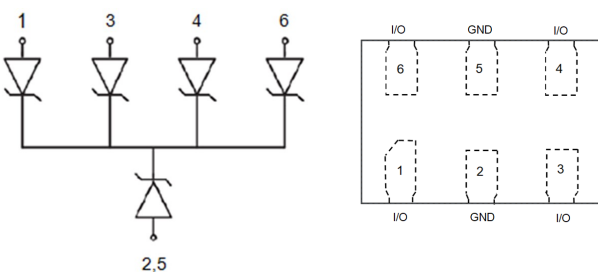
- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- Audio Players
- Keypads, Side Keys, LCD Displays

### Marking Information



33PE = Device Marking Code

### Equivalent Circuit and Pin Configuration



Circuit and Pin Schematic

### Ordering Information

Part Number	Packaging	Reel Size
AU3314PE	3000/Tape & Reel	7 inch

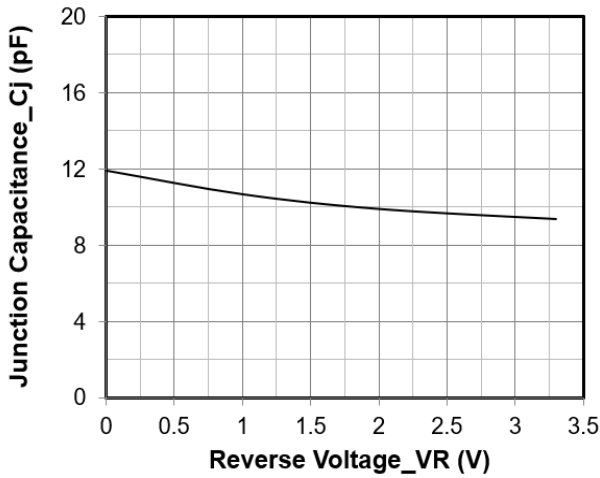
**Absolute Maximum Ratings ( $T_A=25^\circ\text{C}$  unless otherwise specified)**

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 $\mu\text{s}$ )	Ppk	96	W
Peak Pulse Current (8/20 $\mu\text{s}$ )	Ipp	8	A
ESD per IEC 61000-4-2 (Air)	VESD	$\pm 30$	kV
ESD per IEC 61000-4-2 (Contact)		$\pm 30$	
Operating Temperature Range	TJ	-55 to +125	$^\circ\text{C}$
Storage Temperature Range	Tstg	-55 to +150	$^\circ\text{C}$

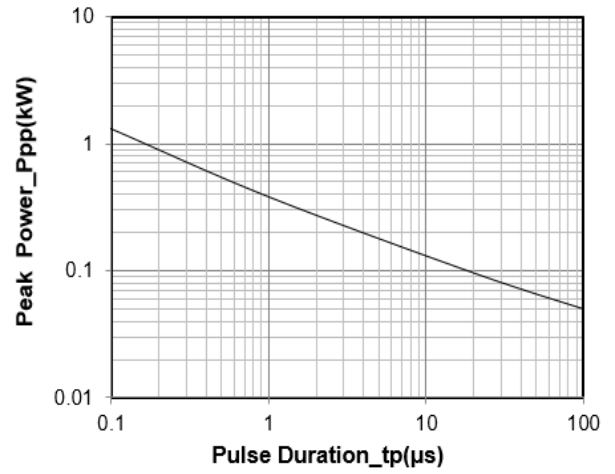
**Electrical Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise specified)**

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			3.3	V	
Breakdown Voltage	VBR	3.5			V	IT = 1mA
Reverse Leakage Current	IR			0.2	$\mu\text{A}$	VRWM = 3.3V
Clamping Voltage	VC			8	V	I <sub>PP</sub> = 1A (8 x 20 $\mu\text{s}$ pulse)
Clamping Voltage	VC			12	V	I <sub>PP</sub> = 8A (8 x 20 $\mu\text{s}$ pulse)
Junction Capacitance	CJ		12		pF	VR = 0V, f = 1MHz

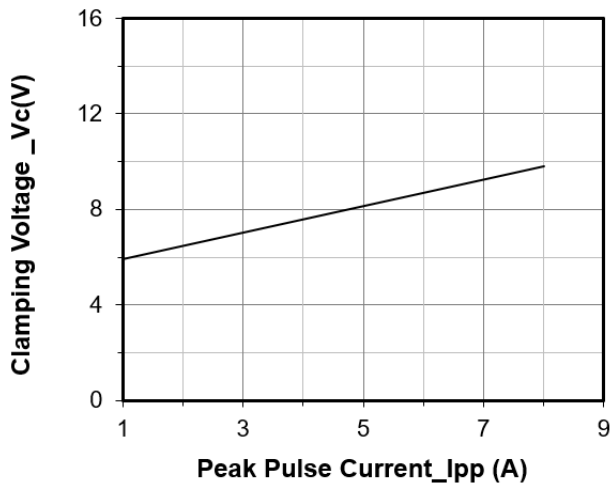
**Typical Performance Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise Specified)**



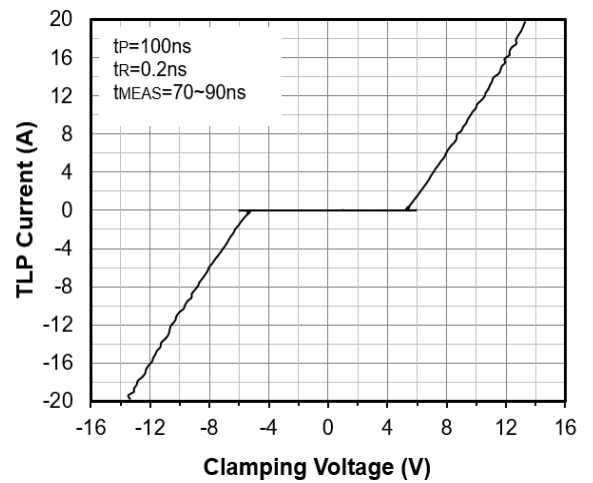
**Junction Capacitance vs. Reverse Voltage**



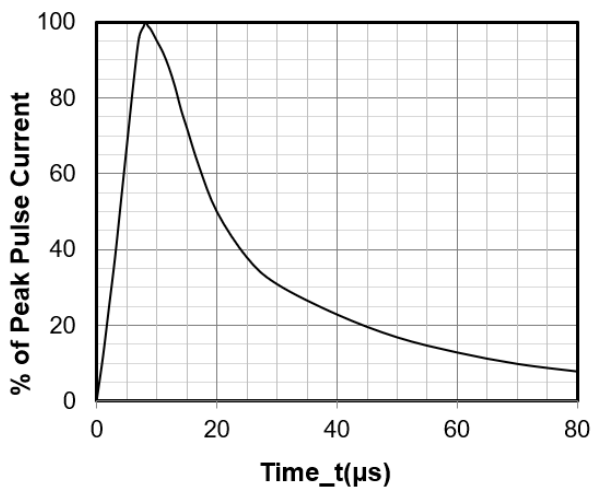
**Peak Pulse Power vs. Pulse Time**



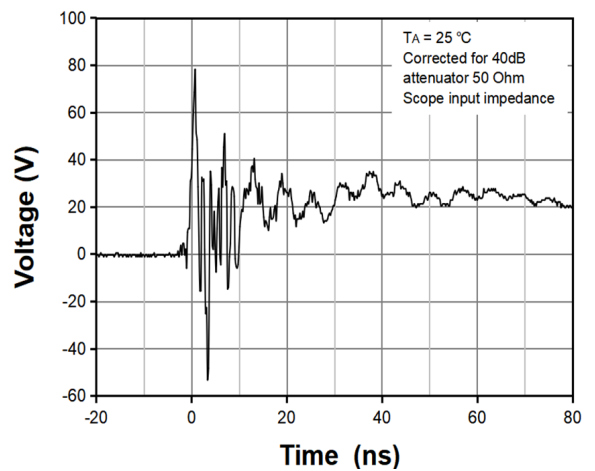
**Clamping Voltage vs. Peak Pulse Current ( $t_p = 8/20\mu\text{s}$ )**



**TLP Measurement**



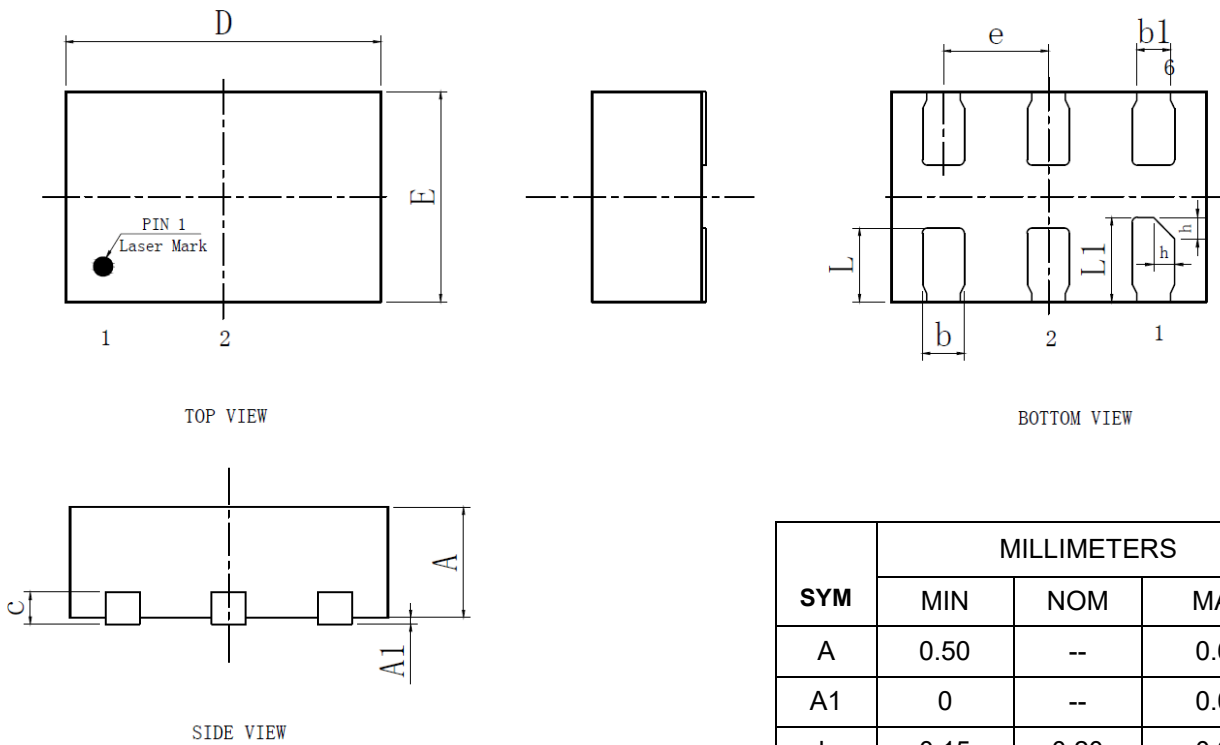
**8 X 20μs Pulse Waveform**



**ESD Clamping Voltage**

**+8 kV Contact per IEC61000-4-2**

### DFN1510-6 Package Outline Drawing



SYM	MILLIMETERS		
	MIN	NOM	MAX
A	0.50	--	0.60
A1	0	--	0.05
b	0.15	0.20	0.25
b1	0.16REF		
c	0.15REF		
D	1.40	1.50	1.60
E	0.90	1.00	1.1
e	0.50BSC		
L	0.30	0.35	0.40
L1	0.35	0.40	0.45
h	0.05	0.01	0.15

### Contact Information

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